
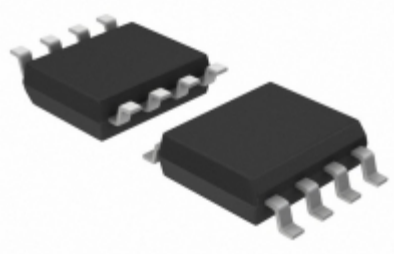
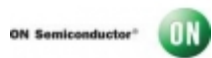
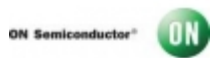
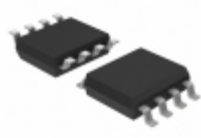
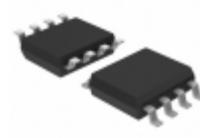



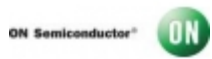
	<h2>NTMD4N03R2G</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTMD4N03R2G</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET 2N-CH 30V 4A 8SOIC</p> <p><b>Datenblätter:</b>  <a href="#">NTMD4N03R2G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 107505 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	NTMD4N03R2G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 30V 4A 8SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	107505 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	2W
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4A
Rds On (Max) @ Id, Vgs	60 mOhm @ 4A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	400pF @ 20V
Verpackung	Tape & Reel (TR)


NTMD4N03R2G ist neu im Original, Suche NTMD4N03R2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMD4N03R2G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMD4N03R2G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTMD4N03</b> AMI Semiconductor / ON Semiconductor NTMD4N03 ON</p>	 <p><b>NTMD5836NL</b> AMI Semiconductor / ON Semiconductor NTMD5836NL ON</p>	 <p><b>NTMD4884NFR2G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 3.3A 8-SOIC</p>	 <p><b>NTMD5836NLR2G</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 40V 9A/5.7A SO-8FL</p>
 <p><b>NTMD5838N</b> VB VB SOP8</p>	 <p><b>NTMD4873NFR2G</b> ON NTMD4873NFR2G ON</p>	 <p><b>NTMD5838NL</b> AMI Semiconductor / ON Semiconductor NTMD5838NL ON</p>	 <p><b>NTMD4N03R2G SOP8</b> AMI Semiconductor / ON Semiconductor NTMD4N03R2G SOP8 ON</p>

### heiße Teile

Mehr

 NTMD2C02R2G	 NTMD2P01R2G	 NTMD3903R2G	 NTMD3N08LR2G	 NTMD3P03
 NTMD3P03R2	 NTMD3P03R2G	 NTMD4102PR2G	 NTMD4184PF	 NTMD4184PFR2G
 NTMD4820N	 NTMD4820NR2G	 NTMD4840N	 NTMD4840NR2G	 NTMD4884NFR2G
 NTMD4N03	 NTMD5836NL	 NTMD5836NLR2G	 NTMD5838NL	 NTMD5838NLR2G
 NTMD6N02	 NTMD6N02DR2G	 NTMD6N02R2G	 NTMD6N03	 NTMD6N03DR2G
 NTMD6N03R2	 NTMD6N03R2G	 NTMD6N04	 NTMD6N04R2G	 NTMD6P02
 NTMD6P02R2	 NTMD6P02R2G	 NTMD6P02R2G.	 NTMD6P02R2SG	 NTMFD4901NF1G
 NTMFD4901NFT1G	 NTMFD4902NF1G	 NTMFD4902NFT1G	 NTMFD4C85NT1G	 NTMFD4C85NTG
 NTMFD4H089NFT1G	 NTMFS4108NT1G	 NTMFS4108NT3G	 NTMFS4119NT3G	 NTMFS4120NT1G
 NTMFS4121NT1G	 NTMFS4701NT1G	 NTMFS4707NT1G	 NTMFS4708NT1G	 NTMFS4709NT1G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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